### VS-VSKDU300/06PbF

**Vishay Semiconductors** 



HEXFRED<sup>®</sup> Ultrafast Diodes, 300 A (INT-A-PAK Power Modules)



INT-A-PAK

PRIMARY CHARACTERISTICS					
V <sub>R</sub>	600 V				
I <sub>F(AV)</sub> at T <sub>C</sub>	300 A at 48 °C				
Package	INT-A-PAK				
Circuit configuration Two diodes doubler circuit					

#### FEATURES

- Electrically insulated by DBC ceramic
- 3500 V<sub>RMS</sub> isolating voltage
- Standard JEDEC<sup>®</sup> package
- Simplified mechanical designs, rapid assembly
- High surge capability
- Large creepage distances
- UL approved file E78996
- Case style INT-A-PAK
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Cathode to anode voltage	V <sub>R</sub>		600	V			
Continuous forward current per leg	L	$T_{\rm C} = 25 \ ^{\circ}{\rm C}$	435				
Continuous forward current per leg	lF	T <sub>C</sub> = 100 °C	230	А			
Single pulse forward current	I <sub>FSM</sub>	Limited by junction temperature	TBD				
Maximum power dissipation per leg	PD	$T_{\rm C} = 25 \ ^{\circ}{\rm C}$	781	W			
Maximum power dissipation per leg		T <sub>C</sub> = 100 °C	313	vv			
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C			
RMS insulation voltage	V <sub>INS</sub>	50 Hz, circuit to base, all terminals shorted, t = 1 s	3500	V			

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Cathode to anode breakdown voltage	V <sub>BR</sub>	I <sub>R</sub> = 500 μA	600	-	-			
	V <sub>FM</sub>	I <sub>F</sub> = 150 A	-	1.23	1.53	v		
Forward voltage drep per leg		I <sub>F</sub> = 300 A	-	1.43	1.96			
Forward voltage drop per leg		I <sub>F</sub> = 150 A, T <sub>J</sub> = 125 °C	-	1.11	1.29			
		I <sub>F</sub> = 300 A, T <sub>J</sub> = 125 °C	-	1.39	1.73			
Maximum reverse leakage current	I <sub>RM</sub>	$T_{\rm J} = 150 \ ^{\circ}{\rm C}, \ V_{\rm R} = 600 \ {\rm V}$	-	-	50	mA		

(Pb) RoHS

COMPLIANT

al level

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS			TYP.	MAX.	UNITS		
		T <sub>J</sub> = 25 °C		-	130	165	ns		
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	195	260			
Dealerseense	I <sub>rr</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 50 A dl/dt = 200 A/μs V <sub>R</sub> = 400 V (per leg)	-	11	18	A nC		
Peak recovery current		T <sub>J</sub> = 125 °C		-	20	30			
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	670	1485			
neverse recovery charge		T <sub>J</sub> = 125 °C		-	1800	3900			
Peak rate of recovery current	dl <sub>(rec)M</sub> /dt	T <sub>J</sub> = 125 °C		-	-	400	A/µs		
Softness factor per leg		$I_F = 50 \text{ A}, T_J = 25 \text{ °C}, \text{ dI/dt} = 400 \text{ A/}\mu\text{s}, V_R = 200 \text{ V}$		-	0.2	-			
Solliess lactor per leg	S	I <sub>F</sub> = 50 A, T <sub>J</sub> = 125 °C, d	-	0.22	-				

THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction operating and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C			
Maximum thermal resistance, junction to case per leg	R <sub>thJC</sub>	DC operation	0.16	K/W			
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	0.05	r////			
Mounting to heatsink		A mounting compound is recommended and the					
torque ± 10 % busbar		torque should be rechecked after a period of 3 hours to allow the spread of the compound.	4 to 6	Nm			
Approximate weight			200	g			
Approximate weight			7.1	oz.			
Case style			INT-A-	PAK			

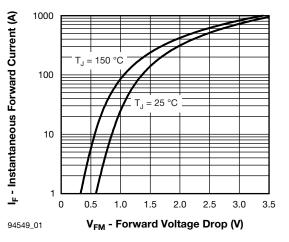
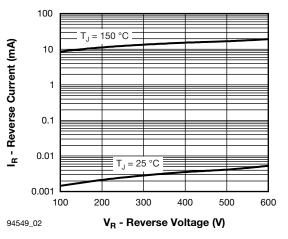


Fig. 1 - Maximum Forward Voltage Drop Characteristics





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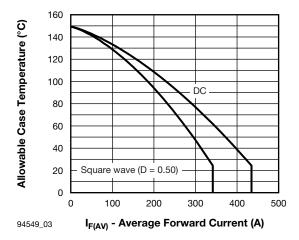


Fig. 3 - Maximum Allowable Case Temperature vs. Average Forward Current

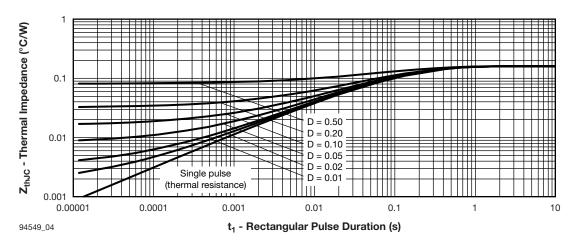


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

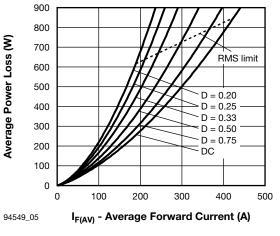


Fig. 5 - Forward Power Loss Characteristics

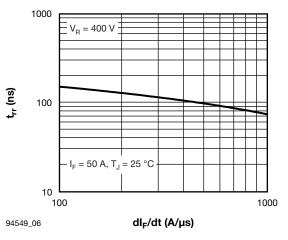


Fig. 6 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt (Per Leg)

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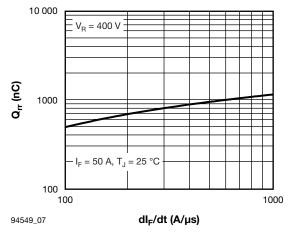


Fig. 7 - Typical Reverse Recovery Charge vs. dl<sub>F</sub>/dt (Per Leg)

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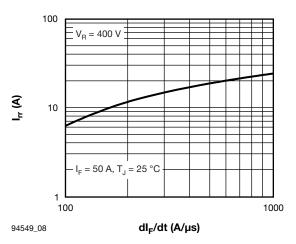
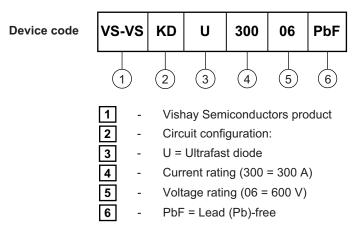


Fig. 8 - Typical Reverse Recovery Current vs. dl<sub>F</sub>/dt (Per Leg)

#### ORDERING INFORMATION TABLE



CIRCUIT CONFIG	URATION
CIRCUIT	CIRCUIT DRAWING
Two diodes doubler circuit	

LINKS TO RELATED DOCUMENTS							
Dimensions www.vishay.com/doc?95254							
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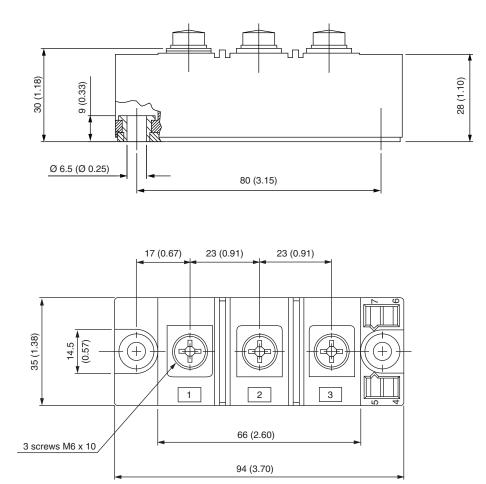


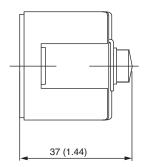
## **Outline Dimensions**

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### **INT-A-PAK DBC**

#### **DIMENSIONS** in millimeters (inches)







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25.163.0653	.1 25.163.2453.0	25.163.4253.0	25.190.2053.0	25.194.3453.0	25.320.4853.1	25.320.5253.1	25.326.3253.1	25.326.3553.1
25.330.1653	.1 25.330.4753.1	25.330.5253.1	25.334.3253.1	25.334.3353.1	25.350.2053.0	25.352.4753.1	25.522.3253.0	<u>T483C</u> <u>T484C</u>
<u>T485F</u> <u>T485</u>	5H T512F-YEB	T513F T514F	<u>T554</u> <u>T612FSE</u>	25.161.3453.0	25.179.2253.0	25.194.3253.0	25.325.1253.1	25.326.4253.1
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25.602.4053	.0							